

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



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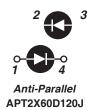
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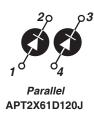
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APT2X61D120J 1200V 53A APT2X60D120J 1200V 53A

DUAL DIE ISOTOP® PACKAGE

ULTRAFAST SOFT RECOVERY RECTIFIER DIODE

PRODUCT APPLICATIONS	PRODUCT FEATURES	PRODUCT BENEFITS
Anti-Parallel Diode -Switchmode Power Supply	Ultrafast Recovery Times	• Low Losses
-Inverters	 Soft Recovery Characteristics 	 Low Noise Switching
Free Wheeling Diode	•	•
-Motor Controllers	 Popular SOT-227 Package 	 Cooler Operation
-Converters		
Snubber Diode	 Low Forward Voltage 	 Higher Reliability Systems
 Uninterruptible Power Supply (UPS) 	3	
• Induction Heating	 High Blocking Voltage 	 Increased System Power
High Speed Rectifiers		Density
- riigii opeca ricotilicis	A Low Lookage Current	

• Low Leakage Current

MAXIMUM RATINGS

All Ratings:	$T_C = 25^{\circ}C$	unless	otherwise	specified.
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Symbol	Characteristic / Test Conditions	APT2X61_60D120J	UNIT
V _R	Maximum D.C. Reverse Voltage		
V _{RRM}	Maximum Peak Repetitive Reverse Voltage	1200	Volts
V _{RWM}	Maximum Working Peak Reverse Voltage		
I _{F(AV)}	Maximum Average Forward Current (T _C = 101°C, Duty Cycle = 0.5)	53	
I _{F(RMS)}	RMS Forward Current (Square wave, 50% duty)	75	Amps
I _{FSM}	Non-Repetitive Forward Surge Current (T _J = 45°C, 8.3ms)	540	
T _J ,T _{STG}	Operating and StorageTemperature Range	-55 to 175	°C
T _L	Lead Temperature for 10 Sec.	300	

STATIC ELECTRICAL CHARACTERISTICS

Symbol	Characteristic / Test Conditions		MIN	TYP	MAX	UNIT
V _F	Forward Voltage	I _F = 60A		2.0	2.5	Volts
		I _F = 120A		2.3		
		I _F = 60A, T _J = 125°C		1.8		
I _{RM} Maximum Rever	Mariana Barras Laskana Ormani	V _R = V _R Rated			250	
	Maximum Reverse Leakage Current	$V_R = V_R$ Rated, $T_J = 125$ °C			500	μA
C _T	Junction Capacitance, V _R = 200V			60		pF

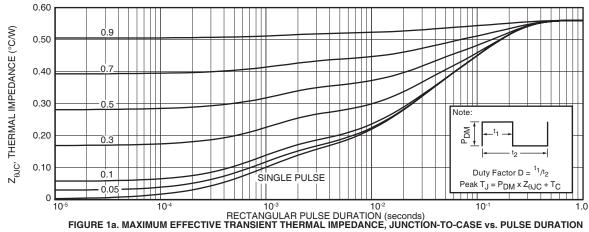
DYNAMIC CHARACTERISTICS

Symbol	Characteristic	Test Conditions	MIN	TYP	MAX	UNIT
t _{rr}	Reverse Recovery Time $I_F = 1A$, $di_F/dt =$	$= -100A/\mu s$, $V_R = 30V$, $T_J = 25^{\circ}C$	-	38		20
t _{rr}	Reverse Recovery Time		-	400		ns
Q _{rr}	Reverse Recovery Charge	$I_F = 60A$, $di_F/dt = -200A/\mu s$	-	1200		nC
I _{RRM}	Maximum Reverse Recovery Current	$V_{R} = 800V, T_{C} = 25^{\circ}C$	-	6	-	Amps
t _{rr}	Reverse Recovery Time	$I_F = 60A$, $di_F/dt = -200A/\mu s$ $V_R = 800V$, $T_C = 125$ °C	-	470		ns
Q _{rr}	Reverse Recovery Charge		-	4000		nC
I _{RRM}	Maximum Reverse Recovery Current		•	13	1	Amps
t _{rr}	Reverse Recovery Time	$I_F = 60A$, $di_F/dt = -1000A/\mu s$ $V_R = 800V$, $T_C = 125^{\circ}C$	-	200		ns
Q _{rr}	Reverse Recovery Charge		-	6200		nC
I _{RRM}	Maximum Reverse Recovery Current		-	47		Amps

THERMAL AND MECHANICAL CHARACTERISTICS

Symbol	Characteristic / Test Conditions	MIN	TYP	MAX	UNIT
$R_{\theta JC}$	Junction-to-Case Thermal Resistance			.56	°C/W
V _{Isolation}	RMS Voltage (50-60hHz Sinusoidal Wavefomr Ffrom Terminals to Mounting Base for 1 Min.)	2500			Volts
W _T Package Weight	Package Weight		1.03		oz
	- Lackage Weight		29.2		g
Torque	Maximum Mounting Torque			10	lb•in
				1.1	N•m

APT Reserves the right to change, without notice, the specifications and information contained herein.



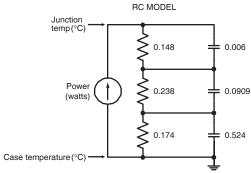
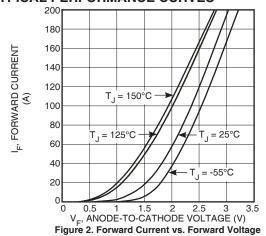


FIGURE 1b, TRANSIENT THERMAL IMPEDANCE MODEL

TYPICAL PERFORMANCE CURVES



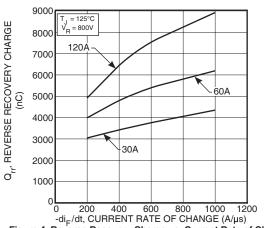
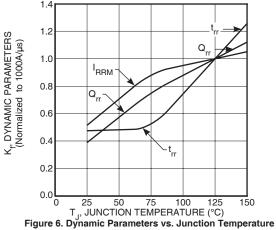
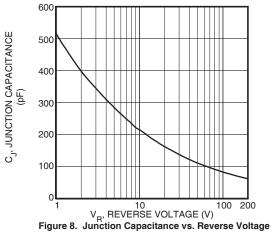


Figure 4. Reverse Recovery Charge vs. Current Rate of Change





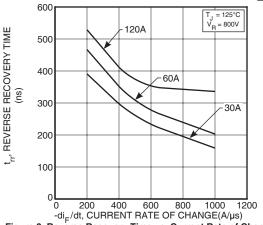


Figure 3. Reverse Recovery Time vs. Current Rate of Change

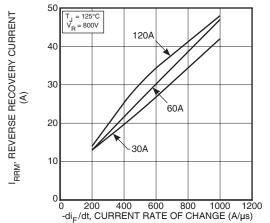


Figure 5. Reverse Recovery Current vs. Current Rate of Change

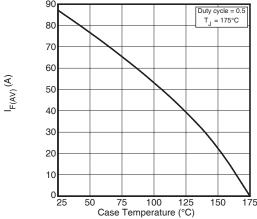


Figure 7. Maximum Average Forward Current vs. CaseTemperature

Figure 9. Diode Test Circuit

- 1 I_F Forward Conduction Current
 2 di_F/dt Rate of Diode Current Change Through Zero Crossing.
 3 I_{RRM} Maximum Reverse Recovery Current.
 4 t_{rr} Reverse Recovery Time, measured from zero crossing where diode current goes from positive to negative, to the point at which the straight line through I_{RRM} and 0.25 I_{RRM} passes through zero.
- 5 Q_{rr} Area Under the Curve Defined by I_{RRM} and t_{rr}.

Figure 10, Diode Reverse Recovery Waveform and Definitions

